

# 7MBR25XKC120-50

IGBT Modules

Power Module(X series)  
1200V / 25A / PIM

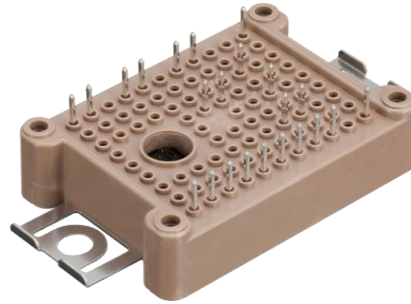
■ Features

- Low  $V_{CE(sat)}$
- Compact Package
- P.C.Board Mount Module
- Converter Diode Bridge Dynamic Brake Circuit
- RoHS compliant Product

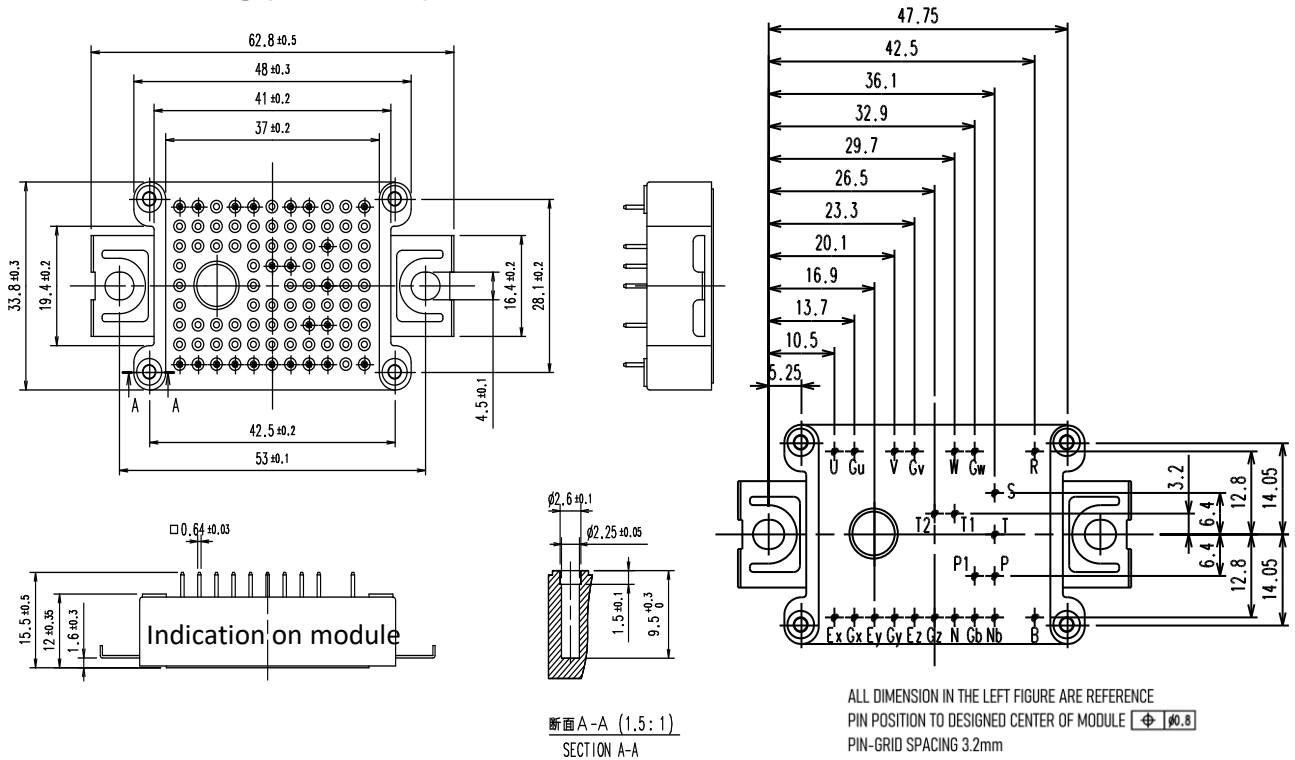
■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply

■ Typical appearance

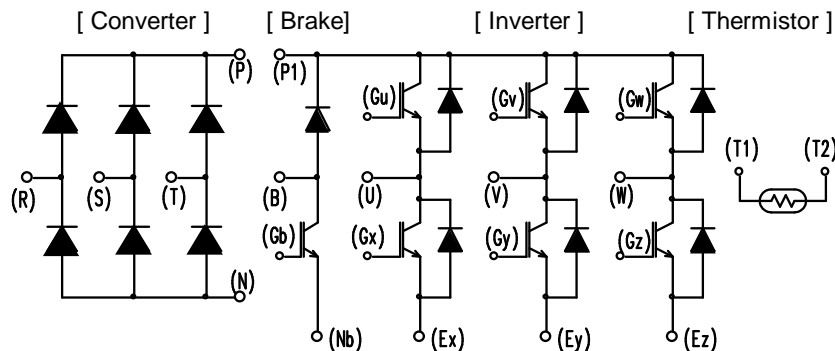


■ Outline drawing ( Unit : mm )



Weight: 25 g (typ.)

■ Equivalent circuit



# 7MBR25XKC120-50

**IGBT Modules**
**■ Maximum ratings ( at  $T_c = 25^\circ\text{C}$  unless otherwise specified )**

Items		Symbols	Conditions		Maximum ratings	Units
Inverter	Collector-Emitter voltage, Gate-Emitter short-circuited	$V_{CES}$			1200	V
	Gate-Emitter voltage, Collector-Emitter short-circuited	$V_{GES}$			$\pm 20$	V
	Collector current	$I_C$	Continuous	$T_c=100^\circ\text{C}$	25	A
	Repetitive peak collector current	$I_{CRM}$	1ms		40	
	Forward current	$I_F$	Continuous		25	
	Repetitive peak forward current	$I_{FRM}$	1ms		40	
	Total power dissipation	$P_{tot}$	1 device		155	W
Brake IGBT	Collector-Emitter voltage, Gate-Emitter short-circuited	$V_{CES}$			1200	V
	Gate-Emitter voltage, Collector-Emitter short-circuited	$V_{GES}$			$\pm 20$	V
	Collector current	$I_C$	Continuous	$T_c=100^\circ\text{C}$	25	A
	Repetitive peak collector current	$I_{CRM}$	1ms		40	
	Total power dissipation	$P_{tot}$	1 device		155	W
Brake FWD	Forward current	$I_F$	Continuous		10	A
	Repetitive peak forward current	$I_{FRM}$	1ms		20	
	Repetitive peak reverse voltage	$V_{RRM}$			1200	V
Converter	Repetitive peak reverse voltage	$V_{RRM}$			1600	V
	Average output current	$I_O$	Three-phase full wave rectified	$T_c=80^\circ\text{C}$	25	A
	Surge current (Non-Repetitive) (*1)	$I_{FSM}$	$t=10\text{ms}$ , Half sine wave form	$T_{vj}=25^\circ\text{C}$	350	A
				$T_{vj}=150^\circ\text{C}$	300	
	$I^2t$ (Non-Repetitive) (*1)	$I^2t$		$T_{vj}=25^\circ\text{C}$	615	A <sup>2</sup> s
				$T_{vj}=150^\circ\text{C}$	450	
Virtual junction temperature		$T_{vj}$	Inverter, Brake		175	°C
			Converter		150	
Operating virtual junction temperature (under switching conditions)		$T_{vjop}$	Inverter, Brake		175	
			Converter		150	
Case temperature		$T_c$			125	
Storage temperature		$T_{stg}$			-40 ~ 125	
Isolation voltage	between terminals and copper base (*2)	$V_{iso}$	A.C. : 1min.		2500	Vrms
	between thermistor and others (*3)					
Screw torque (*4)	Mounting torque of screws to heat sink	$M_s$	M4		1.7	N·m

(\*1)  $T_{vj}$  : Temperature at test start.

(\*2) All terminals should be connected together during the test.

(\*3) Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

(\*4) Recommendable value Mounting 1.3 ~ 1.7 N·m (M4)

# 7MBR25XKC120-50

**IGBT Modules**
**■ Electrical characteristics ( at  $T_{vj} = 25^{\circ}\text{C}$  unless otherwise specified)**

Items	Symbols	Conditions	Characteristics			Units			
			min.	typ.	max.				
Collector-Emitter cut-off current, Gate-Emitter short-circuited	$I_{CES}$	$V_{GE} = 0\text{V}$ $V_{CE} = 1200\text{V}$	-	-	50	$\mu\text{A}$			
Gate leakage current, Collector-Emitter short-circuited	$I_{GES}$	$V_{CE} = 0\text{V}$ $V_{GE} = +20/-20\text{V}$	-	-	100	nA			
Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20\text{V}$ $I_C = 25\text{mA}$	6.0	6.5	7.0	V			
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15\text{V}$ $I_C = 25\text{A}$	$T_{vj}=25^{\circ}\text{C}$	-	1.85	2.30	V		
			$T_{vj}=25^{\circ}\text{C}$	-	1.70	2.15			
	$T_{vj}=125^{\circ}\text{C}$		-	2.20	-				
	$T_{vj}=150^{\circ}\text{C}$		-	2.30	-				
	$T_{vj}=175^{\circ}\text{C}$		-	2.40	-				
Internal gate resistance	$r_g$	-	-	0	-	$\Omega$			
			Capacitance	$C_{ies}$	$V_{CE} = 10\text{V}, V_{GE} = 0\text{V}, f = 1\text{MHz}$	-	2.0	-	nF
						$C_{oes}$	-	0.07	
$C_{res}$	-	0.02				-			
Gate charge	$Q_G$	$V_{CC} = 600\text{V}$ $V_{GE} = -15 \rightarrow +15\text{V}$ $I_C = 25\text{A}$	-	130	-	nC			
Forward voltage	$V_F$ (terminal)	$I_F = 25\text{A}$	$T_{vj}=25^{\circ}\text{C}$	-	2.85	3.30	V		
			$T_{vj}=25^{\circ}\text{C}$	-	2.70	3.15			
	$T_{vj}=125^{\circ}\text{C}$		-	2.95	-				
	$T_{vj}=150^{\circ}\text{C}$		-	2.90	-				
	$T_{vj}=175^{\circ}\text{C}$		-	2.90	-				
Switching time (*1)	$t_{d(on)}$	$V_{CC} = 600\text{V}$ $I_C, I_F = 25\text{A}$ $L_S = 30\text{nH}$ $V_{GE} = +15/-15\text{V}$ $R_G = 20\ \Omega$	$T_{vj}=25^{\circ}\text{C}$	-	0.04	-	$\mu\text{s}$		
			$T_{vj}=125^{\circ}\text{C}$	-	0.04	-			
			$T_{vj}=150^{\circ}\text{C}$	-	0.04	-			
			$T_{vj}=175^{\circ}\text{C}$	-	0.04	-			
	$t_r$	$V_{CC} = 600\text{V}$ $I_C, I_F = 25\text{A}$ $L_S = 30\text{nH}$ $V_{GE} = +15/-15\text{V}$ $R_G = 20\ \Omega$	$T_{vj}=25^{\circ}\text{C}$	-	0.02	-			
			$T_{vj}=125^{\circ}\text{C}$	-	0.03	-			
			$T_{vj}=150^{\circ}\text{C}$	-	0.03	-			
			$T_{vj}=175^{\circ}\text{C}$	-	0.03	-			
	$t_{d(off)}$	$V_{CC} = 600\text{V}$ $I_C, I_F = 25\text{A}$ $L_S = 30\text{nH}$ $V_{GE} = +15/-15\text{V}$ $R_G = 20\ \Omega$	$T_{vj}=25^{\circ}\text{C}$	-	0.15	-			
			$T_{vj}=125^{\circ}\text{C}$	-	0.19	-			
			$T_{vj}=150^{\circ}\text{C}$	-	0.20	-			
			$T_{vj}=175^{\circ}\text{C}$	-	0.20	-			
$t_f$	$V_{CC} = 600\text{V}$ $I_C, I_F = 25\text{A}$ $L_S = 30\text{nH}$ $V_{GE} = +15/-15\text{V}$ $R_G = 20\ \Omega$	$T_{vj}=25^{\circ}\text{C}$	-	0.15	-				
		$T_{vj}=125^{\circ}\text{C}$	-	0.17	-				
		$T_{vj}=150^{\circ}\text{C}$	-	0.20	-				
		$T_{vj}=175^{\circ}\text{C}$	-	0.21	-				
Reverse recovery time	$t_{rr}$	$V_{CC} = 600\text{V}$ $I_C, I_F = 25\text{A}$ $L_S = 30\text{nH}$ $V_{GE} = +15/-15\text{V}$ $R_G = 20\ \Omega$	$T_{vj}=25^{\circ}\text{C}$	-	0.06	-			
			$T_{vj}=125^{\circ}\text{C}$	-	0.11	-			
			$T_{vj}=150^{\circ}\text{C}$	-	0.13	-			
			$T_{vj}=175^{\circ}\text{C}$	-	0.16	-			

(\*1) Turn on time ( $t_{on}$ ) =  $t_{d(on)} + t_r$ , Turn off time ( $t_{off}$ ) =  $t_{d(off)} + t_f$

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**IGBT Modules**

Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Inverter Switching loss (per pulse)	$E_{on}$	$V_{CC} = 600V$ $I_C, I_F = 25A$ $L_s = 30nH$ $V_{GE} = +15/-15 V$ $R_G = 20 \Omega$	$T_{vj} = 25^\circ C$	-	1.51	-	mJ
			$T_{vj} = 125^\circ C$	-	1.95	-	
			$T_{vj} = 150^\circ C$	-	2.07	-	
			$T_{vj} = 175^\circ C$	-	2.19	-	
	$E_{off}$	$V_{CC} = 600V$ $I_C, I_F = 25A$ $L_s = 30nH$ $V_{GE} = +15/-15 V$ $R_G = 20 \Omega$	$T_{vj} = 25^\circ C$	-	1.79	-	
			$T_{vj} = 125^\circ C$	-	2.30	-	
			$T_{vj} = 150^\circ C$	-	2.43	-	
			$T_{vj} = 175^\circ C$	-	2.54	-	
	$E_{rr}$	$V_{CC} = 600V$ $I_C, I_F = 25A$ $L_s = 30nH$ $V_{GE} = +15/-15 V$ $R_G = 20 \Omega$	$T_{vj} = 25^\circ C$	-	1.00	-	
			$T_{vj} = 125^\circ C$	-	1.27	-	
			$T_{vj} = 150^\circ C$	-	1.47	-	
			$T_{vj} = 175^\circ C$	-	1.66	-	
Collector-Emitter cut-off current, Gate-Emitter short-circuited	$I_{CES}$	$V_{GE} = 0V$ $V_{CE} = 1200V$	-	-	50	$\mu A$	
Gate leakage current, Collector-Emitter short-circuited	$I_{GES}$	$V_{CE} = 0V, V_{GE} = +20/-20V$	-	-	100	nA	
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15V$ $I_C = 25A$	$T_{vj} = 25^\circ C$	-	1.85	2.30	V
			$T_{vj} = 25^\circ C$	-	1.70	2.15	
	$V_{CE(sat)}$ (chip)		$T_{vj} = 125^\circ C$	-	2.20	-	
			$T_{vj} = 150^\circ C$	-	2.30	-	
Internal gate resistance	$r_g$	-	$T_{vj} = 25^\circ C$	-	0	-	$\Omega$
			$T_{vj} = 25^\circ C$	-	0	-	
			$T_{vj} = 125^\circ C$	-	0	-	
			$T_{vj} = 150^\circ C$	-	0	-	
Brake Switching time (*1)	$t_{d(on)}$	$V_{CC} = 600V$ $I_C = 25A$ $L_s = 30nH$ $V_{GE} = +15/-15 V$ $R_G = 20 \Omega$	$T_{vj} = 25^\circ C$	-	0.04	-	$\mu s$
			$T_{vj} = 125^\circ C$	-	0.04	-	
			$T_{vj} = 150^\circ C$	-	0.04	-	
			$T_{vj} = 175^\circ C$	-	0.04	-	
	$t_r$	$V_{CC} = 600V$ $I_C = 25A$ $L_s = 30nH$ $V_{GE} = +15/-15 V$ $R_G = 20 \Omega$	$T_{vj} = 25^\circ C$	-	0.02	-	
			$T_{vj} = 125^\circ C$	-	0.03	-	
			$T_{vj} = 150^\circ C$	-	0.03	-	
			$T_{vj} = 175^\circ C$	-	0.03	-	
	$t_{d(off)}$	$V_{CC} = 600V$ $I_C = 25A$ $L_s = 30nH$ $V_{GE} = +15/-15 V$ $R_G = 20 \Omega$	$T_{vj} = 25^\circ C$	-	0.15	-	
			$T_{vj} = 125^\circ C$	-	0.19	-	
			$T_{vj} = 150^\circ C$	-	0.20	-	
			$T_{vj} = 175^\circ C$	-	0.20	-	
$t_f$	$V_{CC} = 600V$ $I_C = 25A$ $L_s = 30nH$ $V_{GE} = +15/-15 V$ $R_G = 20 \Omega$	$T_{vj} = 25^\circ C$	-	0.15	-		
		$T_{vj} = 125^\circ C$	-	0.17	-		
		$T_{vj} = 150^\circ C$	-	0.20	-		
		$T_{vj} = 175^\circ C$	-	0.21	-		
Reverse current	$I_{RRM}$	$V_R = 1200V$	-	-	50	$\mu A$	
Forward voltage	$V_F$ (terminal)	$I_F = 10A$	$T_{vj} = 25^\circ C$	-	2.05	2.50	V
			$T_{vj} = 25^\circ C$	-	1.90	2.35	
	$V_F$ (chip)		$T_{vj} = 125^\circ C$	-	1.95	-	
			$T_{vj} = 150^\circ C$	-	1.90	-	
Reverse current	$I_{RRM}$	$V_R = 1600V$	$T_{vj} = 25^\circ C$	-	-	50	$\mu A$
			$T_{vj} = 25^\circ C$	-	-	50	
			$T_{vj} = 125^\circ C$	-	-	50	
			$T_{vj} = 150^\circ C$	-	-	50	
Continuous (direct) forward voltage	$V_F$	$I_F = 25A$	terminal	-	1.20	1.65	V
			chip	-	1.05	1.50	
Resistance	$R$	$T = 25^\circ C$	-	5000	-	$\Omega$	
		$T = 100^\circ C$	465	495	520		
B value	$B$	$T = 25/ 50^\circ C$	3305	3375	3450	K	

(\*1) Turn on time ( $t_{on}$ ) =  $t_{d(on)}$  +  $t_r$ , Turn off time ( $t_{off}$ ) =  $t_{d(off)}$  +  $t_f$ 
**FM6M01725b**

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**IGBT Modules**
**NOTICE:**

The external gate resistance ( $R_G$ ) shown above is one of our recommended value for the purpose of minimum switching loss. However the optimum  $R_G$  depends on circuit configuration and/or environment. We recommend that the  $R_G$  has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

**■ Thermal resistance characteristics**

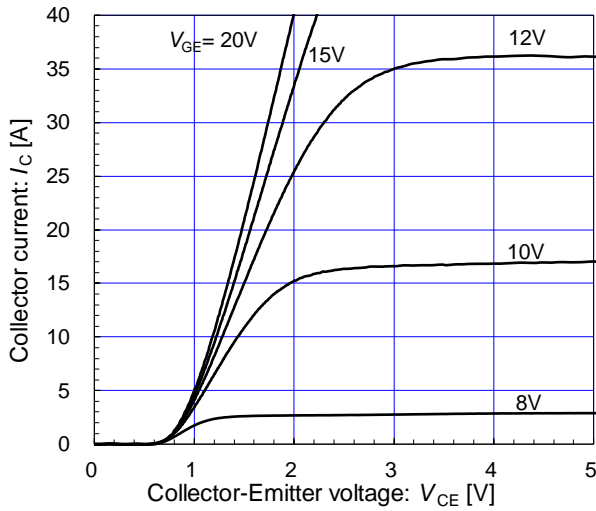
Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance junction to case (1 device)	$R_{th(j-c)}$	Inverter IGBT	-	-	0.94	K/W
		Inverter FWD	-	-	1.75	
		Brake IGBT	-	-	0.94	
		Brake FWD	-	-	1.75	
		Converter Diode	-	-	0.97	
Thermal resistance case to heat sink(*1) (1 device)	$R_{th(c-f)}$	Inverter IGBT	-	0.74	-	
		Inverter FWD	-	0.92	-	
		Brake IGBT	-	0.78	-	
		Brake FWD	-	0.75	-	
		Converter Diode	-	0.78	-	

(\*1) This is the value which is defined mounting on the additional cooling fin with 1 W/(m·K) thermal grease.

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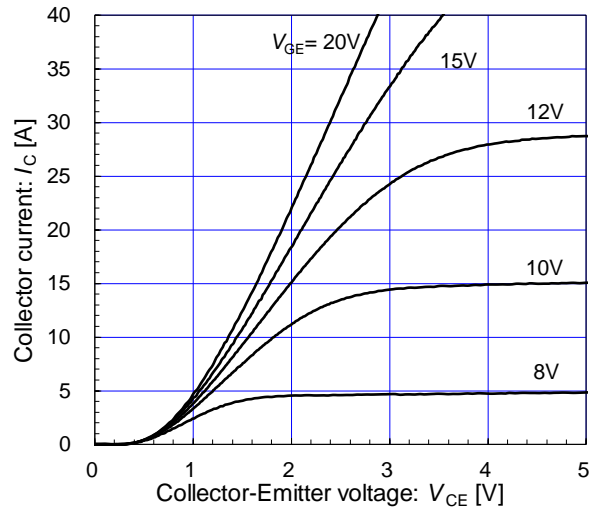
[ Inverter ]

Collector current vs. Collector-Emittor voltage (typ.)  
 $T_{vj} = 25^{\circ}\text{C} / \text{chip}$



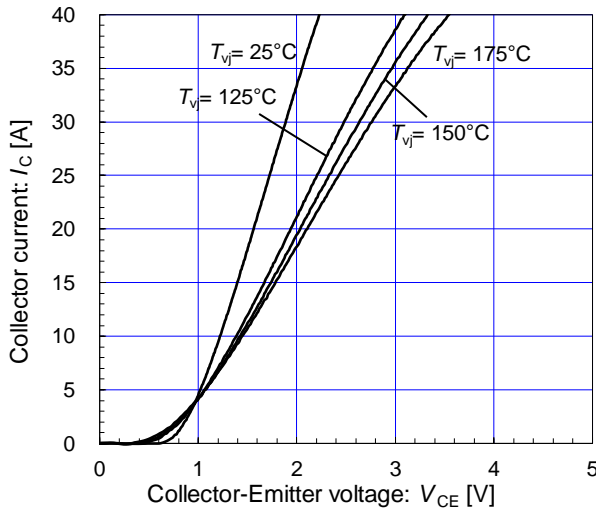
[ Inverter ]

Collector current vs. Collector-Emittor voltage (typ.)  
 $T_{vj} = 175^{\circ}\text{C} / \text{chip}$



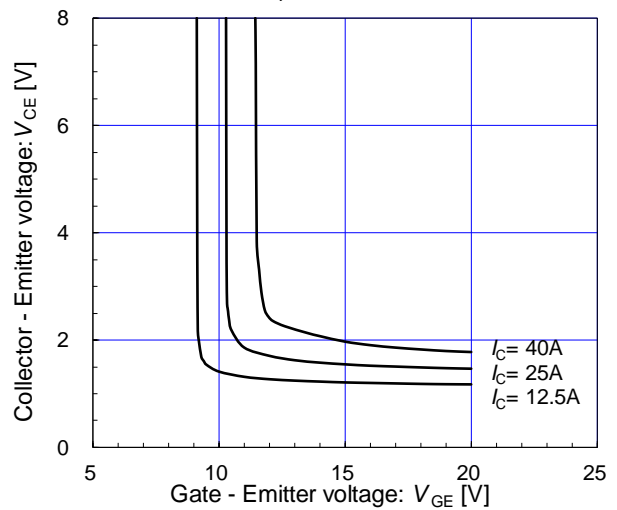
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Collector current vs. Collector-Emittor voltage (typ.)  
 $V_{GE} = 15\text{V} / \text{chip}$



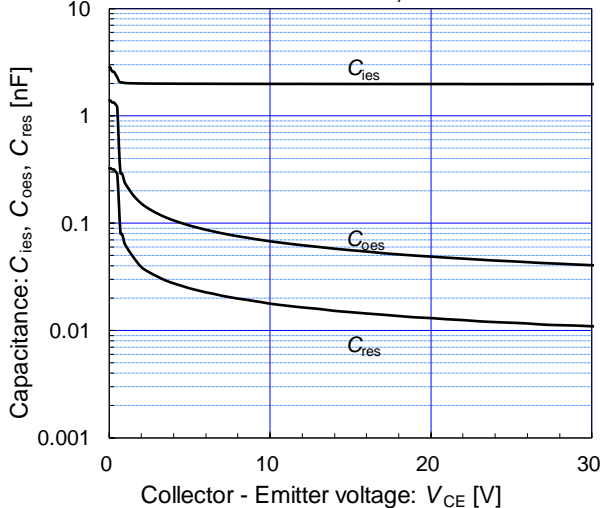
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Collector-Emittor voltage vs. Gate-Emittor voltage (typ.)  
 $T_{vj} = 25^{\circ}\text{C} / \text{chip}$



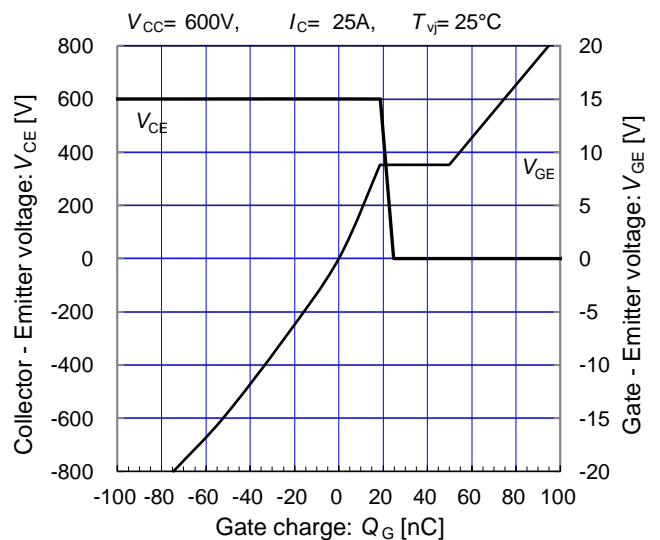
[ Inverter ]

Capacitance vs. Collector-Emittor voltage (typ.)  
 $V_{GE} = 0\text{V}, f = 1\text{MHz}, T_{vj} = 25^{\circ}\text{C}$

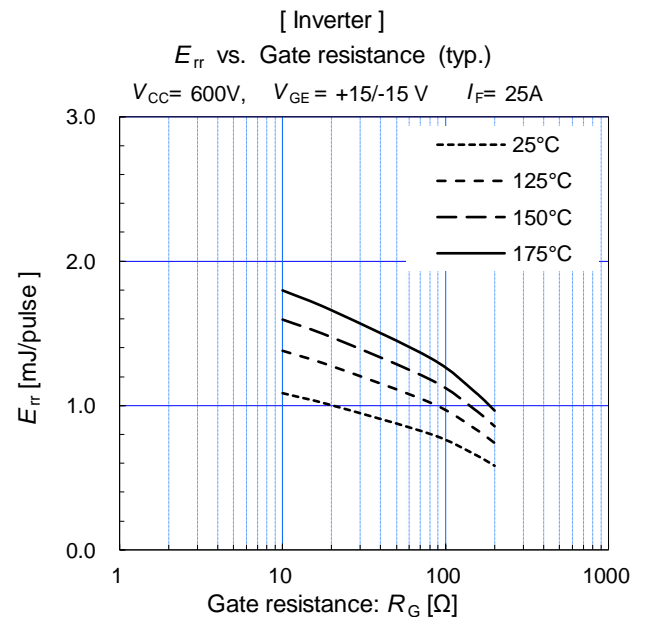
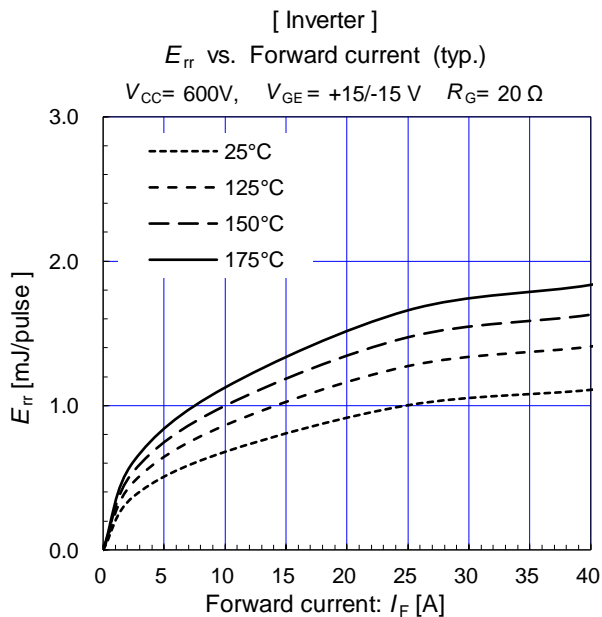
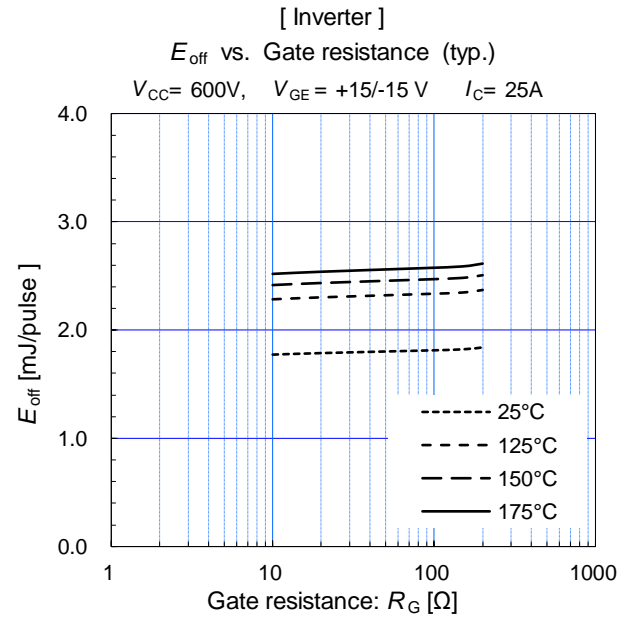
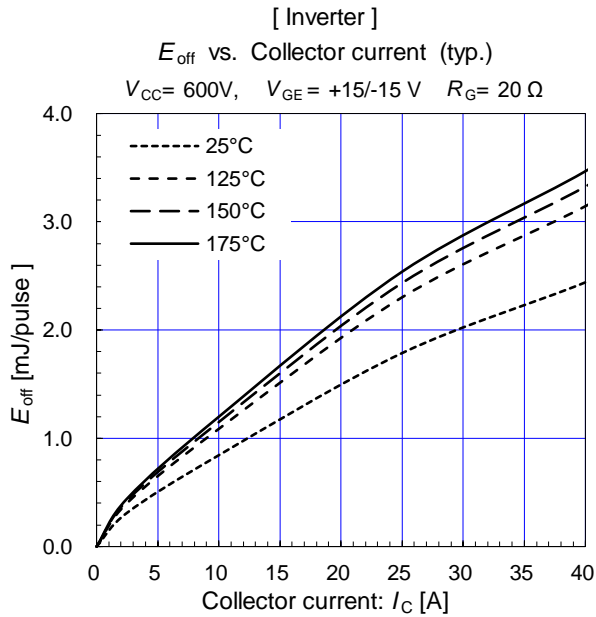
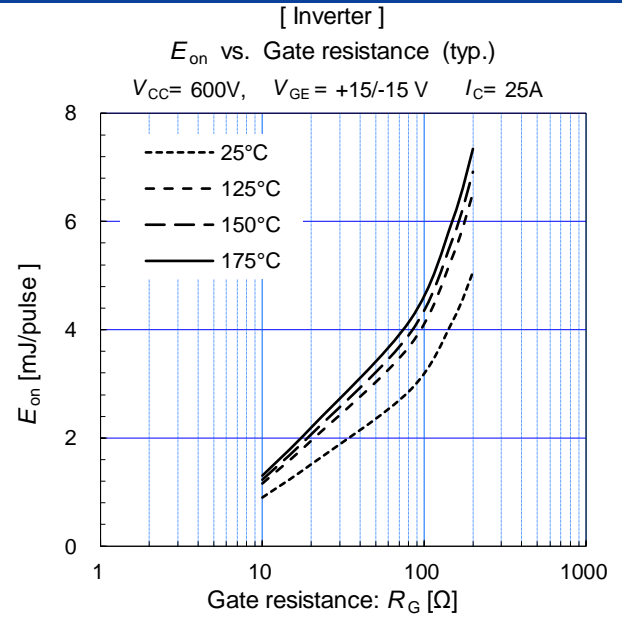
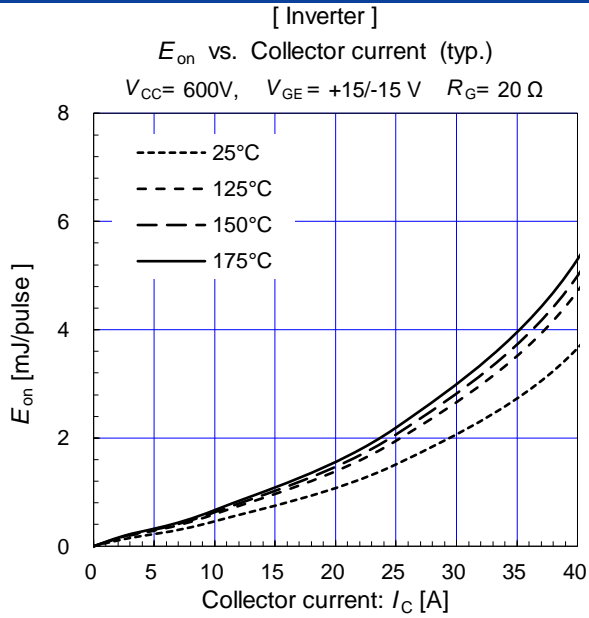


[ Inverter ]

Dynamic gate charge (typ.)



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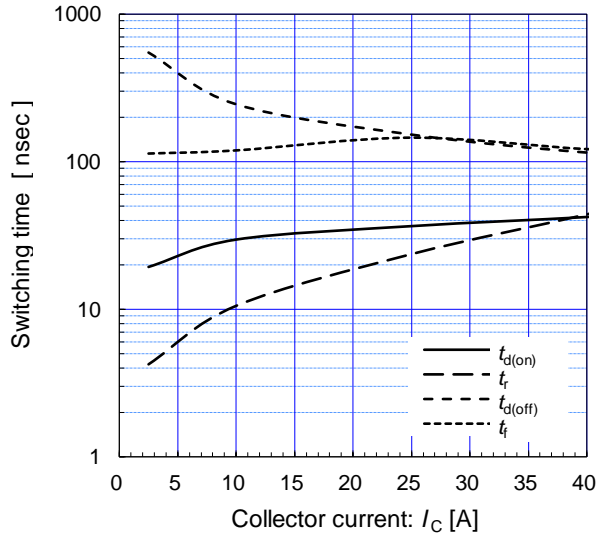


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IGBT Modules

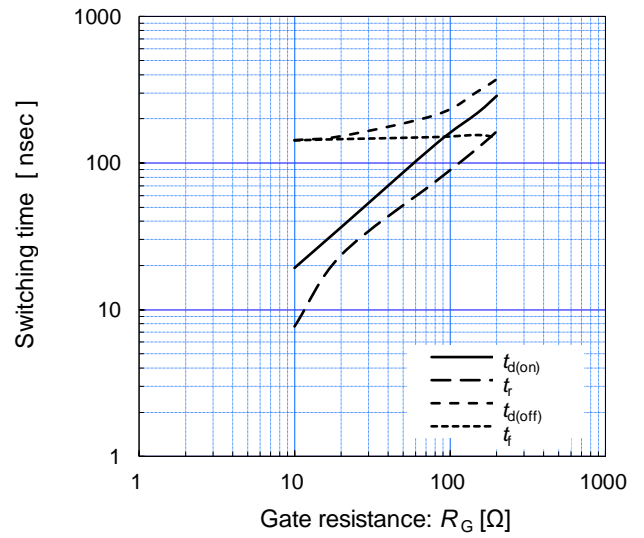
[ Inverter ]

Switching time vs. Collector current (typ.)  
 $V_{CC}=600V, R_G=20\Omega, V_{GE}=+15/-15V, T_{vj}=25^\circ C$



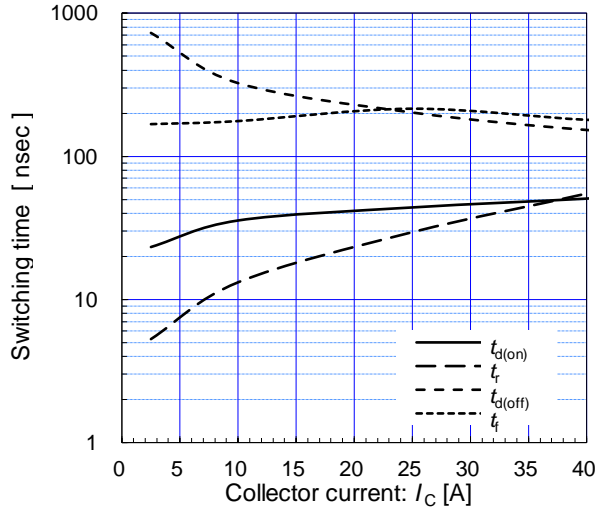
[ Inverter ]

Switching time vs. Gate resistance (typ.)  
 $V_{CC}=600V, I_C=25A, V_{GE}=+15/-15V, T_{vj}=25^\circ C$



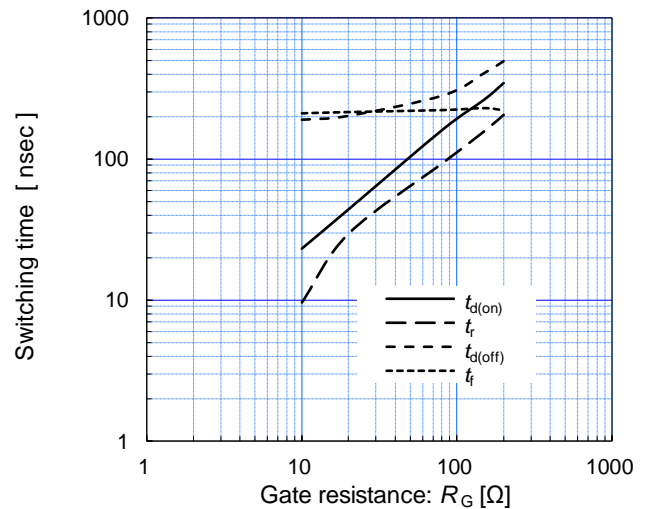
[ Inverter ]

Switching time vs. Collector current (typ.)  
 $V_{CC}=600V, R_G=20\Omega, V_{GE}=+15/-15V, T_{vj}=175^\circ C$



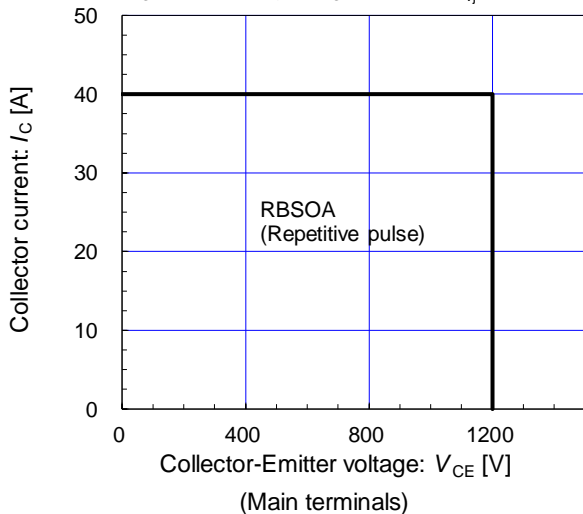
[ Inverter ]

Switching time vs. Gate resistance (typ.)  
 $V_{CC}=600V, I_C=25A, V_{GE}=+15/-15V, T_{vj}=175^\circ C$



[ Inverter ]

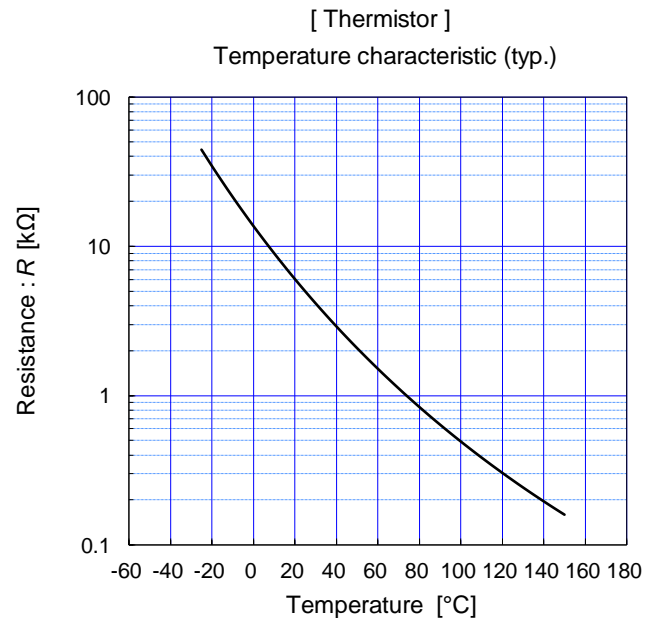
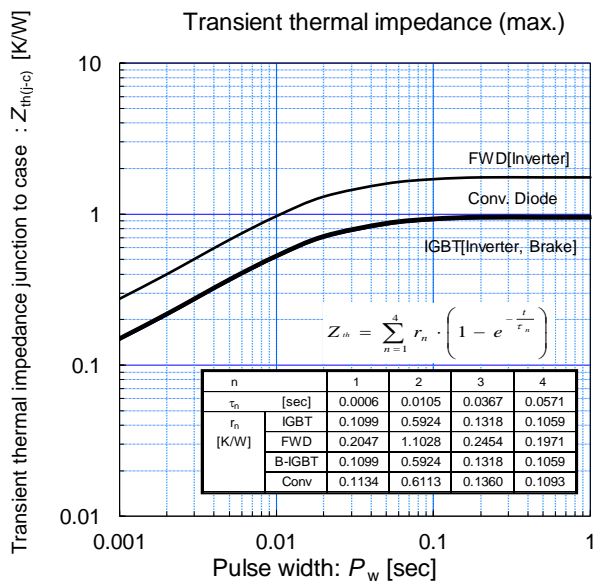
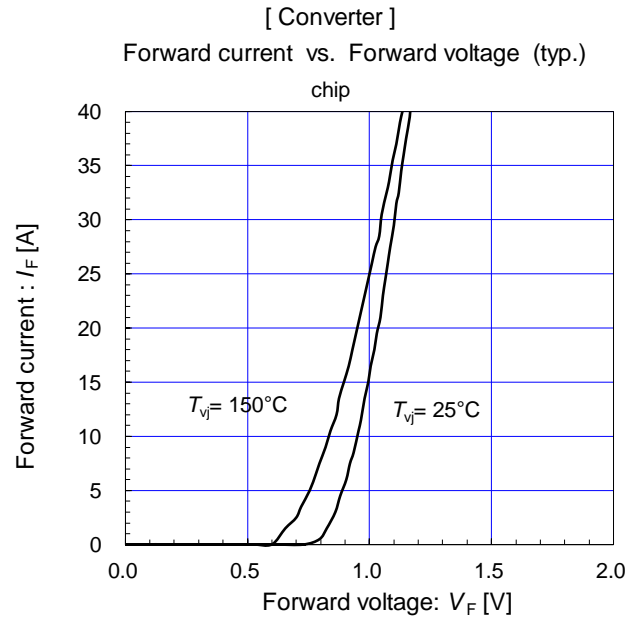
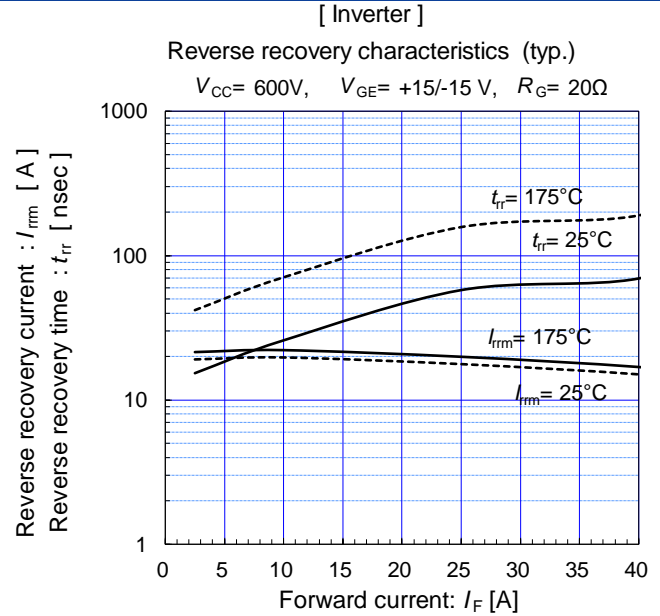
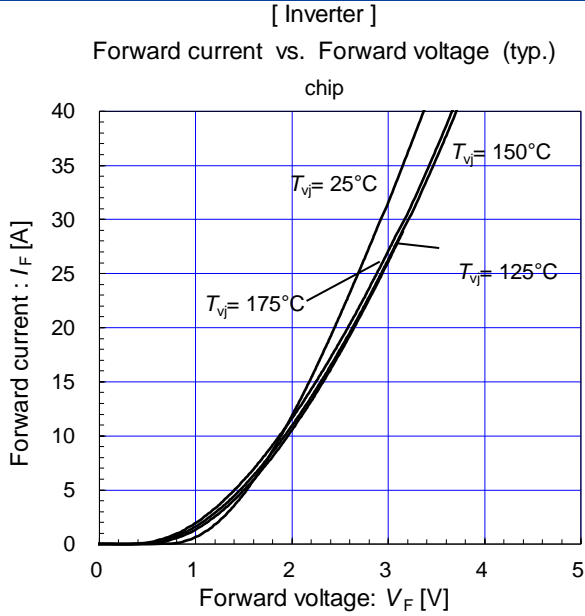
Reverse bias safe operating area (max.)  
 $V_{GE}=+15/-15V, R_G \geq 20\Omega, T_{vj}=175^\circ C$



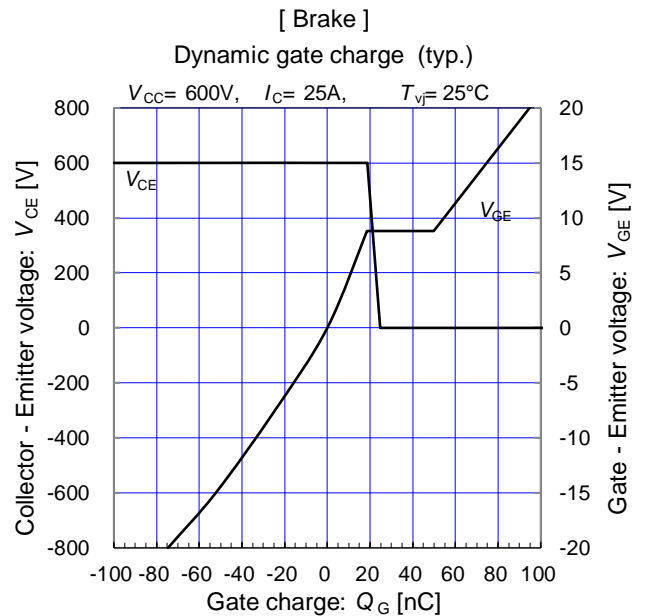
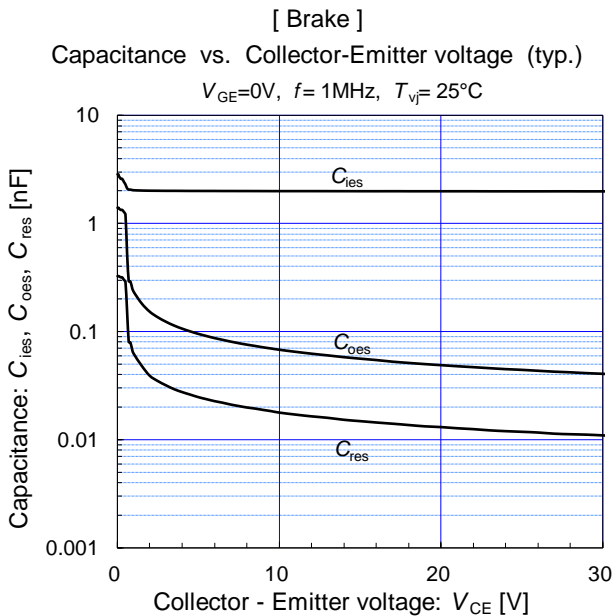
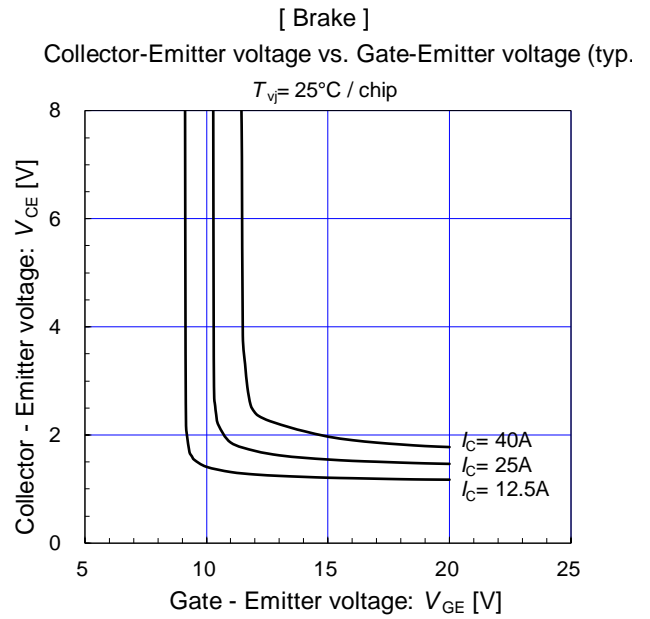
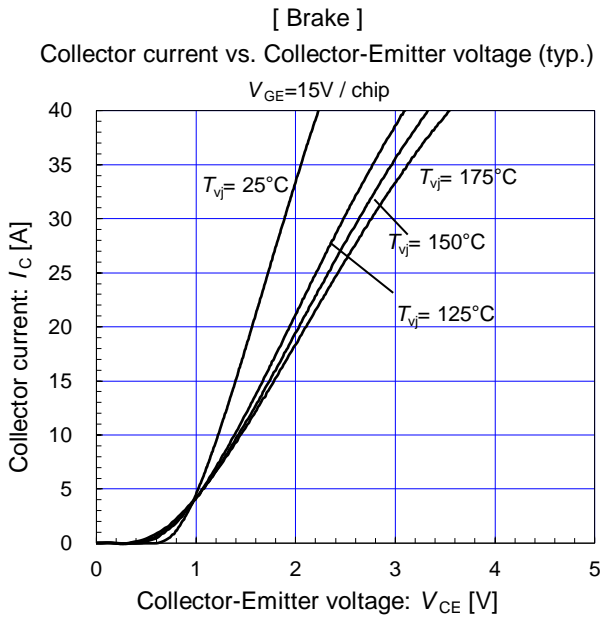
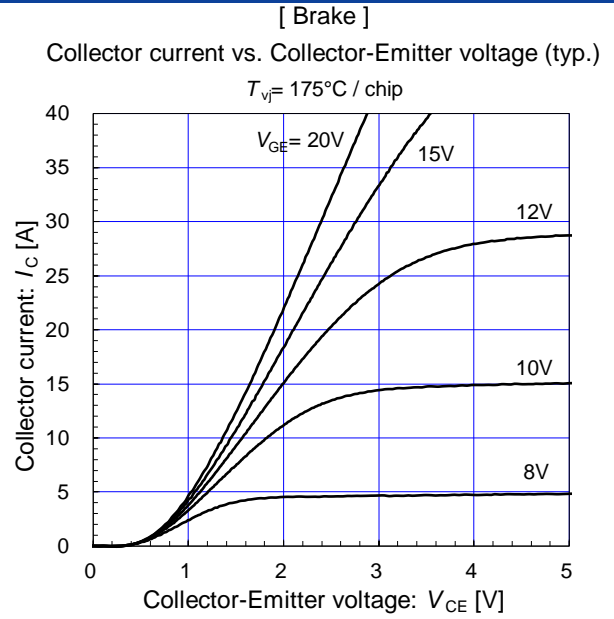
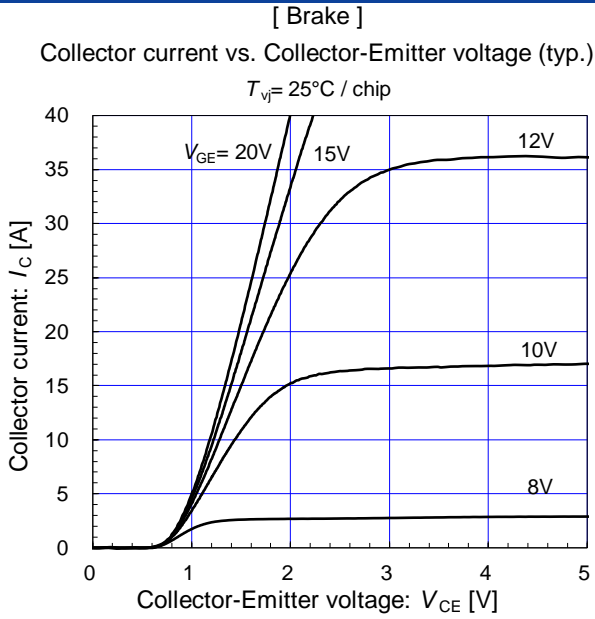


# 7MBR25XKC120-50

IGBT Modules



# 7MBR25XKC120-50



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